Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current, per IEC 61000-4-5	I_{PP}	6	A	I/O to V_{SS}, 8/20µs
Peak Pulse Power, per IEC 61000-4-5	P_{PP}	60	W	I/O to V_{SS}, 8/20µs
Operating Voltage (DC)	V_{DC}	6	V	I/O to V_{SS}
ESD Protection – Contact Discharge, per IEC 61000-4-2	$V_{ESD\_CONTACT}$	+20/-16	kV	I/O to V_{SS}
ESD Protection – Air Discharge, per IEC 61000-4-2	V_{ESD_AIR}	+20/-18	kV	I/O to V_{SS}
Operating Temperature	T_{OP}	-55 to +85	°C	—
Storage Temperature	T_{STG}	-55 to +150	°C	—

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	P_D	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	$R_{\theta JA}$	360	°C/W

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Reverse Working Voltage	V_{RWM}	—	—	5.5	V	—
Reverse Current (Note 6)	I_R	—	—	50	nA	V_R = 5V, I/O to V_{SS}
Reverse Breakdown Voltage	V_{BR}	6	—	—	V	I_R = 1mA, I/O to V_{SS}
Forward Clamping Voltage	V_F	-1.0	-0.85	—	V	I_F = -15mA, I/O to V_{SS}
Holding Voltage	V_H	5.5	—	—	V	—
Reverse Clamping Voltage (Note 7)	V_C	—	6.4	—	V	I_{PP} = 1A, I/O to V_{SS}, 8/20µs
Reverse Clamping Voltage (Note 7)	V_C	—	9	10	V	I_{PP} = 6A, I/O to V_{SS}, 8/20µs
Trigger Voltage	V_{TRIG}	—	—	9.5	V	—
ESD Clamping Voltage	V_{ESD}	—	9	—	V	TLP, 10A, t_P = 100ns, I/O to V_{SS}
Dynamic Reverse Resistance	R_{DIF-R}	—	0.25	—	Ω	TLP, 10A, t_P = 100ns, I/O to V_{SS}
Dynamic Forward Resistance	R_{DIF-F}	—	0.25	—	Ω	TLP, 10A, t_P = 100ns, V_{SS} to I/O
Channel Input Capacitance	$C_{I/O}$	—	0.5	0.65	pF	$V_{I/O}$ = 2.5V, V_{SS} = 0V, f = 1MHz

Notes:
5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.
6. Short duration pulse test used to minimize self-heating effect.
7. Clamping voltage value is based on an 8x20µs peak pulse current (I_{pp}) waveform.

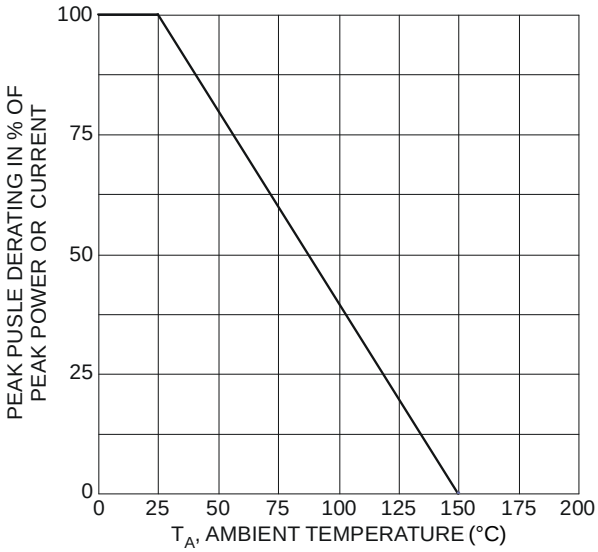


Figure 1 Pulse Derating Curve

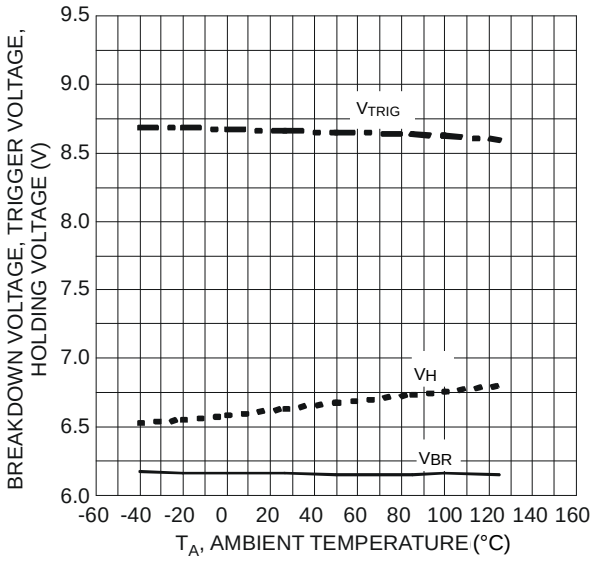


Figure 2 BV, Trigger Voltage, Holding Voltage vs. Ambient Temperature

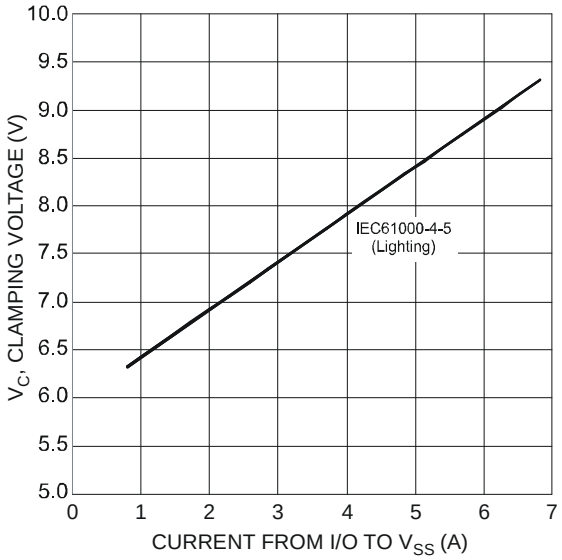


Figure 3 Clamping Voltage Characteristic

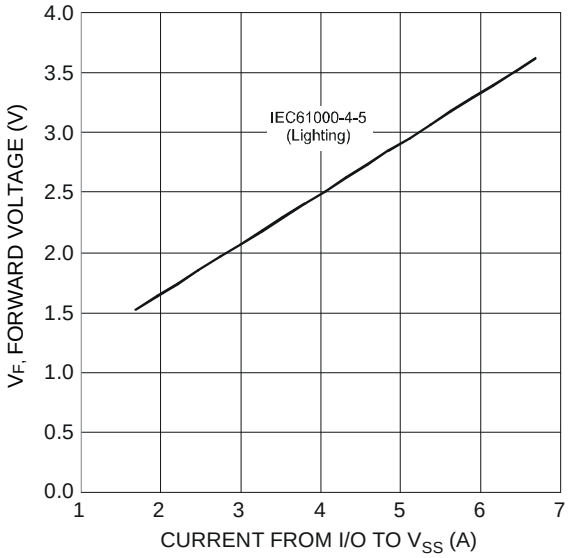


Figure 4 Forward Voltage Characteristic

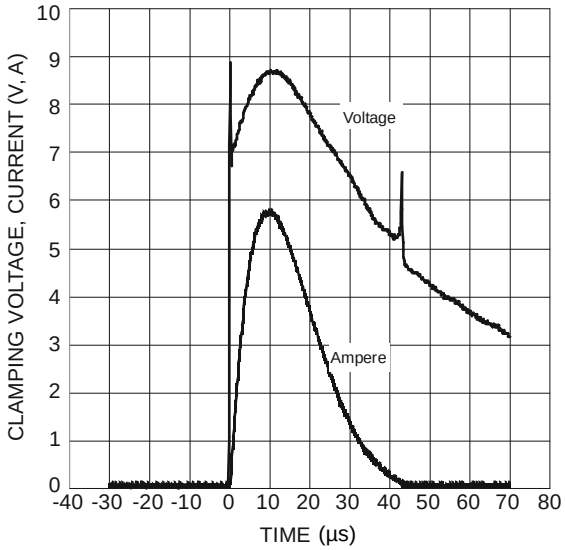


Figure 5 Waveform of Clamping Voltage, Current vs. Time (8/20µs, I/O to V_{SS})

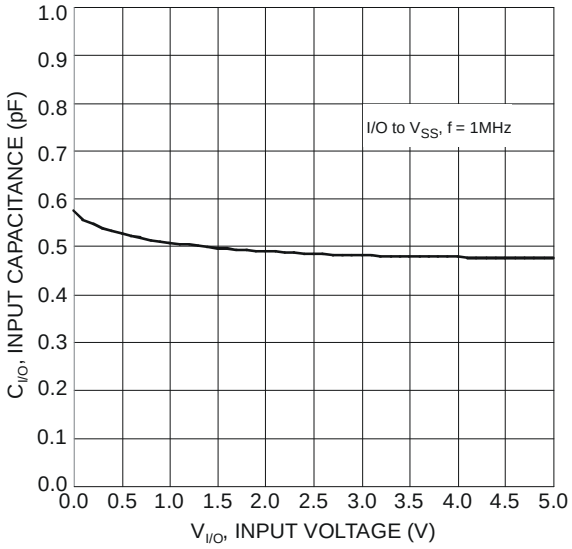


Figure 6 Input Capacitance vs. Input Voltage

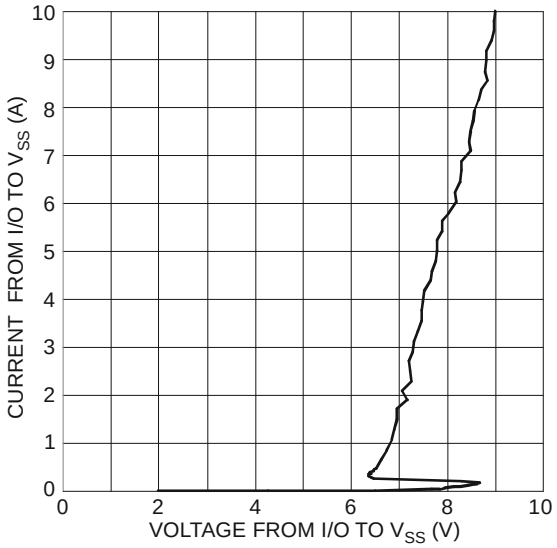
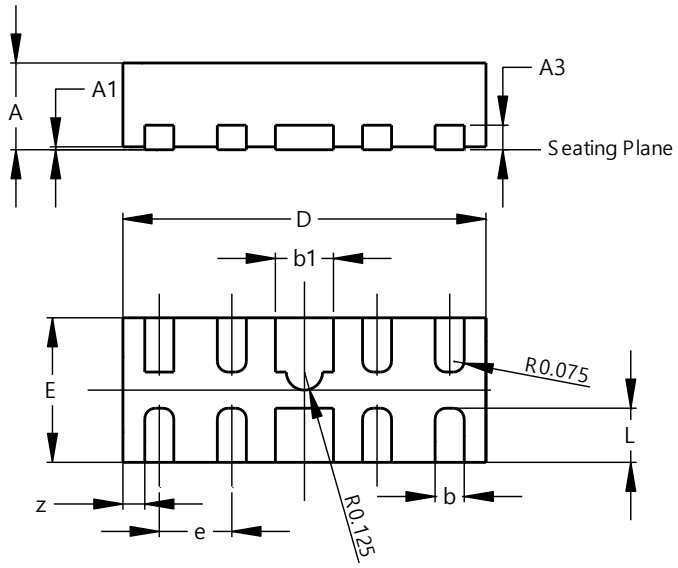


Figure 7 Current vs. Voltage

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2510-10

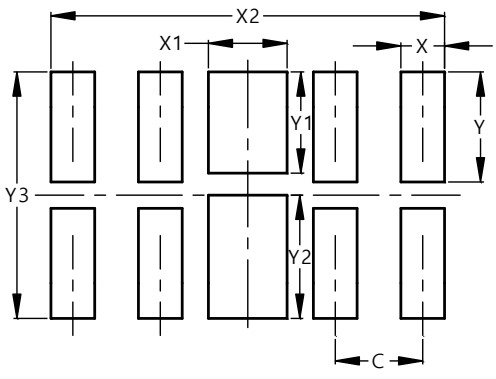


U-DFN2510-10			
Dim	**Min**	**Max**	**Typ**
A	0.545	0.605	0.575
A1	0.00	0.05	0.03
A3	-	-	0.13
b	0.15	0.25	0.20
b1	0.35	0.45	0.40
D	2.450	2.575	2.500
e	-	-	0.50
E	0.950	1.075	1.000
L	0.325	0.425	0.375
z	-	-	0.150
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2510-10



Dimensions	Value (in mm)
C	0.500
X	0.250
X1	0.450
X2	2.250
Y	0.625
Y1	0.575
Y2	0.700
Y3	1.400

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